

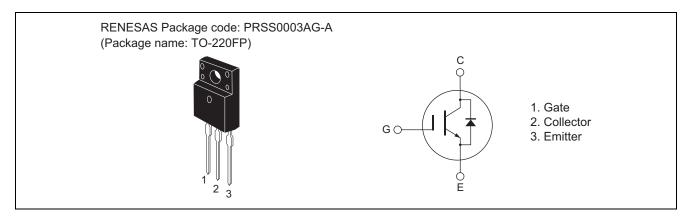
RJH60D2DPP-E0

600V - 12A - IGBT Application: Inverter R07DS0894EJ0100 Rev.1.00 Nov 01, 2012

Features

- Short circuit withstand time (5 µs typ.)
- Low collector to emitter saturation voltage $V_{CE(sat)} = 1.7 \text{ V}$ typ. (at $I_C = 12 \text{ A}$, $V_{GE} = 15 \text{ V}$, $Ta = 25^{\circ}\text{C}$)
- Built in fast recovery diode (100 ns typ.) in one package
- Trench gate and thin wafer technology
- High speed switching t_f = 80 ns typ. (at V_{CC} = 300 V, V_{GE} = 15 V, I_C = 12 A, Rg = 5 Ω , Ta = 25°C, inductive load)

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item		Symbol	Ratings	Unit
Collector to emitter voltage / diode reverse voltage		V _{CES} / V _R	600	V
Gate to emitter voltage		V_{GES}	±30	V
Collector current	Tc = 25°C	I _C	25	A
	Tc = 100°C	I _C	12	A
Collector peak current		ic(peak) Note1	50	A
Collector to emitter diode forward current		i _{DF}	12	A
Collector to emitter diode forward peak current		i _{DF} (peak) Note1	50	A
Collector dissipation		P _C Note2	34	W
Junction to case thermal resistance (IGBT)		θj-c Note2	3.7	°C/W
Junction to case thermal resistance (Diode)		θj-cd Note2	4.9	°C/W
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 $\mu s,$ duty cycle \leq 1%

2. Value at Tc = 25°C

Electrical Characteristics

 $(Ta = 25^{\circ}C)$

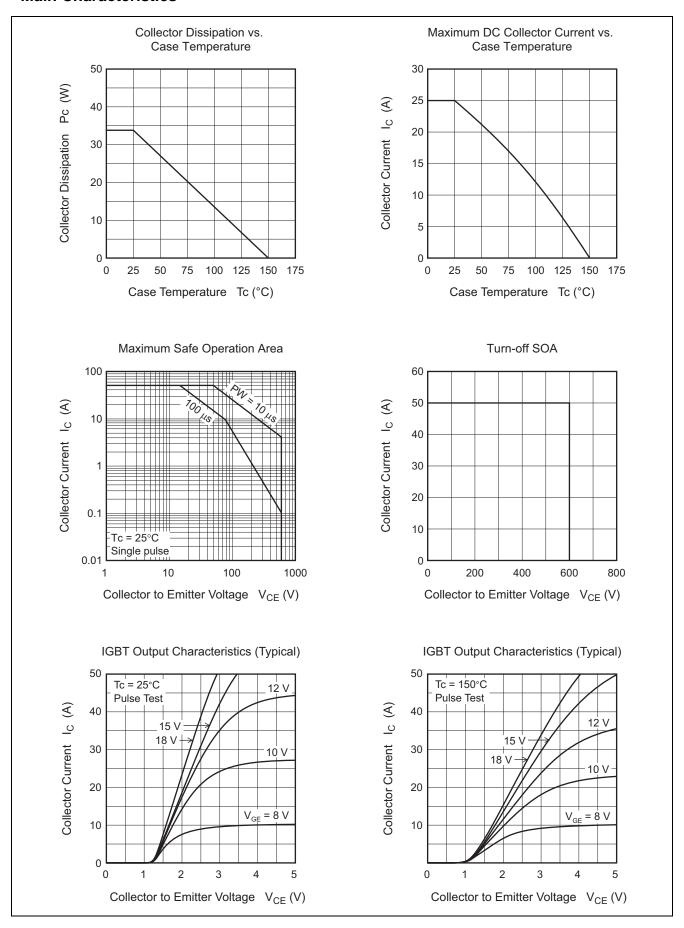
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Collector to emitter breakdown voltage	V _{BR(CES)}	600	_	_	V	$I_C = 10 \mu A, V_{GE} = 0$
Zero gate voltage collector current / Diode reverse current	I _{CES} / I _R	_	_	5	μА	V _{CE} = 600 V, V _{GE} = 0
Gate to emitter leak current	I _{GES}	_	_	±1	μΑ	$V_{GE} = \pm 30 \text{ V}, V_{CE} = 0$
Gate to emitter cutoff voltage	$V_{GE(off)}$	4.0	_	6.0	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$
Collector to emitter saturation voltage	V _{CE(sat)}	_	1.7	2.2	V	$I_C = 12 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$
	V _{CE(sat)}	_	2.2	_	V	$I_C = 25 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$
Input capacitance	Cies	_	430	_	pF	V _{CE} = 25 V
Output capacitance	Coes	_	40	_	pF	V _{GE} = 0 f = 1 MHz
Reveres transfer capacitance	Cres	_	12	_	pF	
Total gate charge	Qg	_	19	_	nC	V _{GE} = 15 V
Gate to emitter charge	Qge	_	4	_	nC	$V_{CE} = 300 \text{ V}$
Gate to collector charge	Qgc	_	7	_	nC	I _C = 12 A
Turn-on delay time	t _{d(on)}	_	32	_	ns	V _{CC} = 300 V
Rise time	t _r	_	13	_	ns	V _{GE} = 15 V
Turn-off delay time	t _{d(off)}	_	85	_	ns	$I_C = 12 \text{ A}$ $Rg = 5 \Omega$ Inductive load
Fall time	t _f	_	80	_	ns	
Turn-on energy	Eon	_	0.10	_	mJ	
Turn-off energy	E _{off}	_	0.16	_	mJ	
Total switching energy	E _{total}	_	0.26	_	mJ	
Short circuit withstand time	t _{sc}	3.0	5.0	_	μS	$V_{CC} \le 360 \text{ V}, V_{GE} = 15 \text{ V}$
	•		•			•
FRD Forward voltage	V _F	_	1.2	1.6	V	I _F = 12 A ^{Note3}
FRD reverse recovery time	t _{rr}	_	100	_	ns	I _F = 12 A
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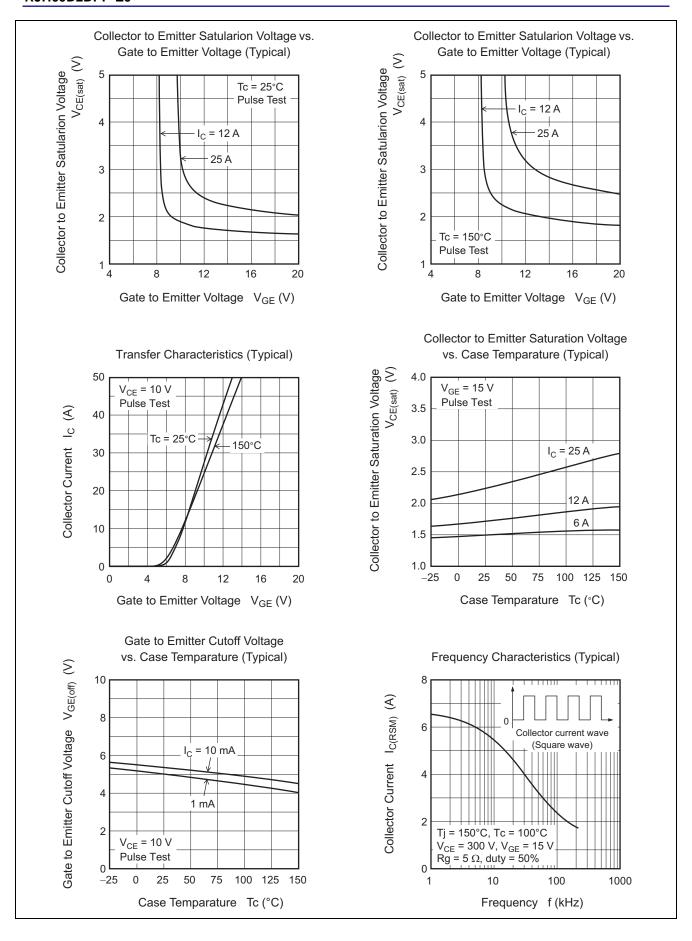
FRD reverse recovery charge Q_{rr} 0.2 μС FRD peak reverse recovery current I_{rr} 5.0 Α

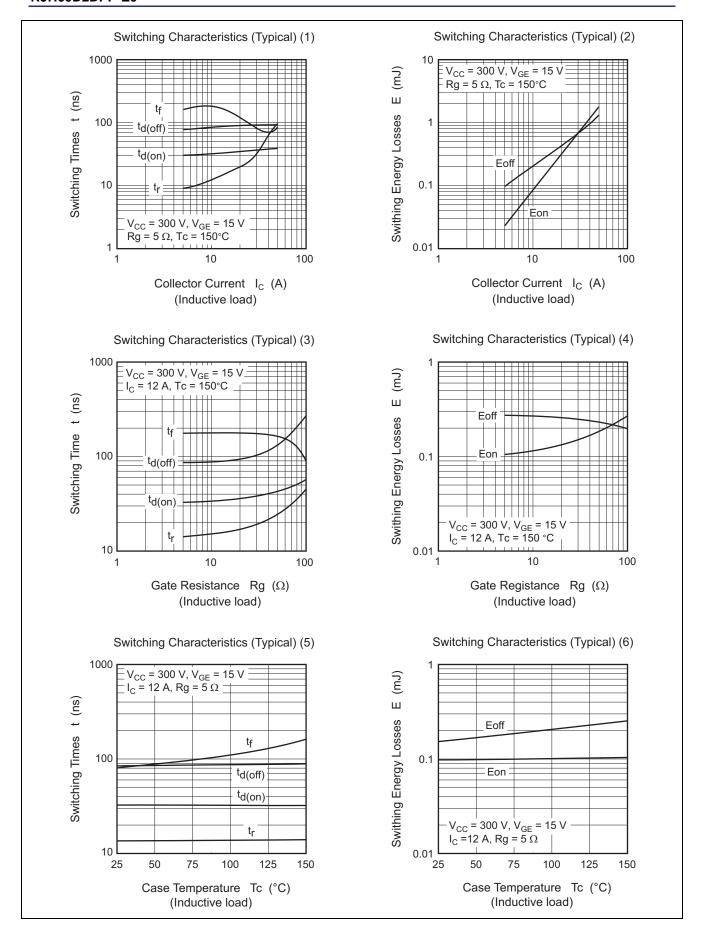
 $di_F/dt = 100 A/\mu s$

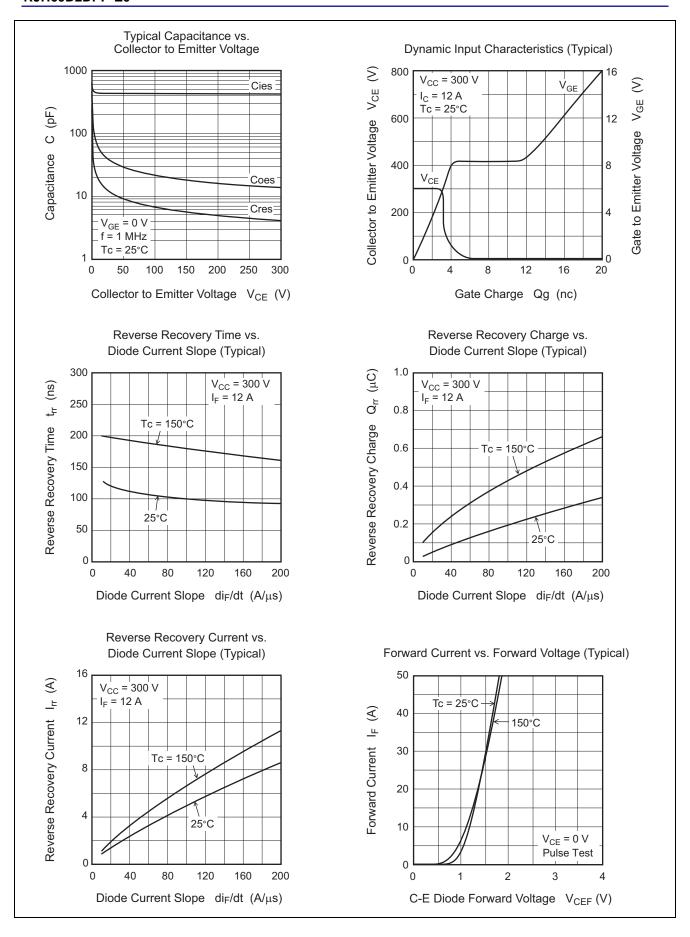
Notes: 3. Pulse test.

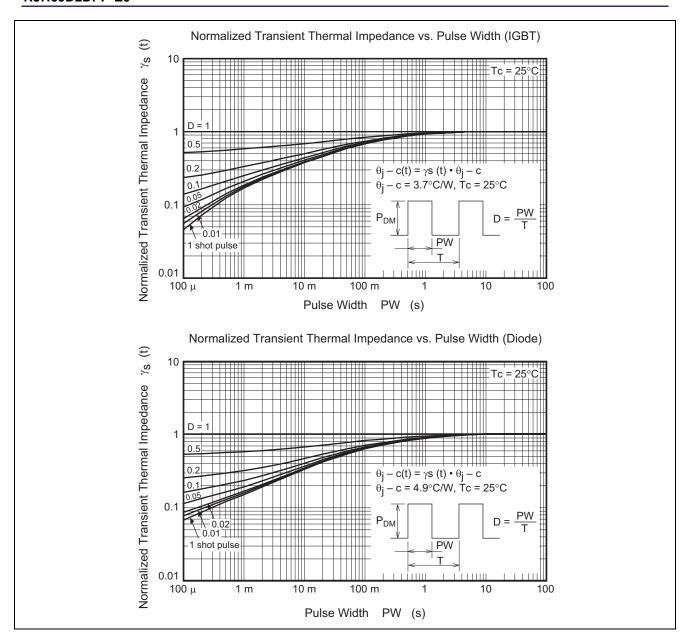
Main Characteristics

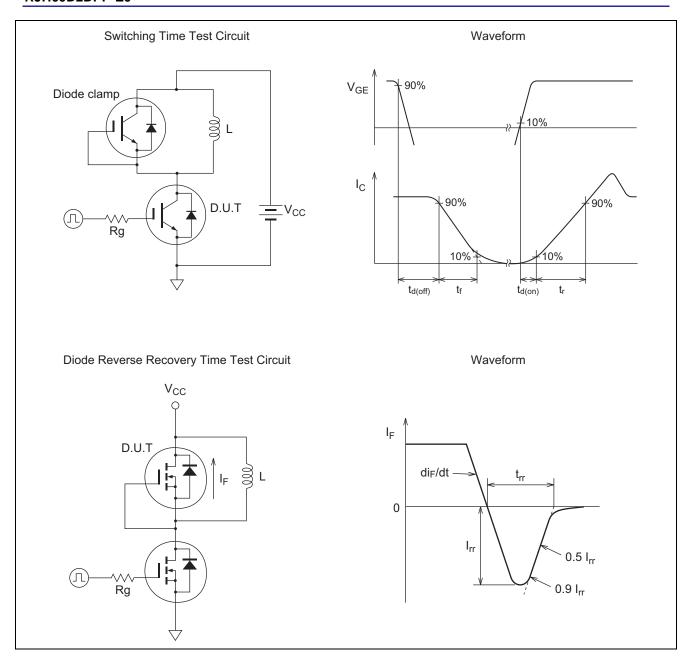




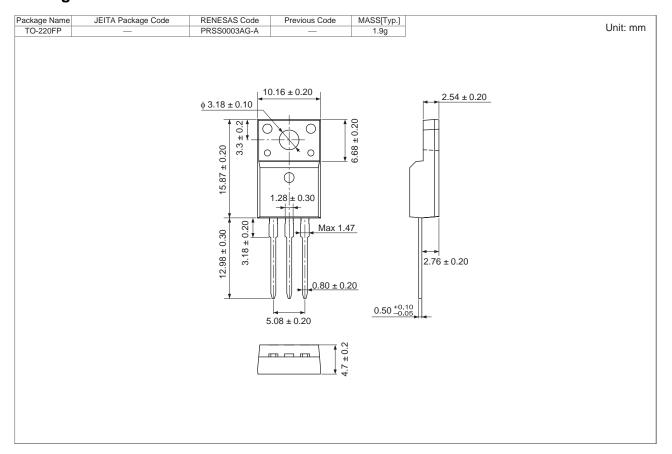








Package Dimension



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJH60D2DPP-E0#T2	1000 pcs	Box (Tube)

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